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ARTICLE TYPE

High-performance humidity sensors from Ni(SO4)0.3(OH)1.4 nanobelts

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 $\mathbb{E} \{Ni(SO_4)_{0.3}(OH)_{1.4}$ nanobelts were synthesized by a facile **hydrothermal method. Humidity sensors based on Ni(SO⁴)0.3(OH)1.4 nanobelts were fabricated and exhibited high sensitivity and fast response. It also showed good longterm stability. The high performance could be related to the** ¹⁰**high surface to volume ratio of nanobelts and the chemical composition of Ni** $(SO_4)_{0.3} (OH)_{1.4}$ **.**

Humidity displays an extensive influence on human comfort, industry manufacturing and packaging, medical care, meteorological forecast and so on. $1-5$ There is a substantial 15 interest in the development of sensors for application in monitoring and detecting humidities in moisture-sensitive environment, such as glove boxes and clean rooms.

It has shown that nanomaterial-based devices have great potential for humidity sensors. Various methods have been 20 developed.⁶⁻¹⁰ One dimensional (1D) nanomaterials offer a promising platform for high-performance sensing devices that employ favourable electronic transport. With large surface to volume ratio, they are expected to behave high performance because of more active sites available on the surface of the

25 material for physical or chemical interaction.¹¹⁻¹³ Many humidity sensors based on 1D nanomaterials have been reported.¹⁴⁻¹⁸ But it is still a big challenge for the realization of sensors with high sensitivity, fast response, long-term stability, low cost and facile fabrication technique. Novel 30 materials are being explored.¹⁹

Nickel hydroxide has attracted great interest as cathode material in alkaline batteries. $20-23$ Being intercalated with anions or water molecules, it will form hydroxyl-rich nickel basic salts, having a composition of -Ni(A^{n−})_{x/n}(OH)_{2−x}·yH₂O

35 (where $x=0.5~1$, $A=NO³$, Cl, $SO₄²$).²⁴⁻²⁵ Nanostructures of these salts have been realized. $Ni(SO₄)_{0.3}(OH)_{1.4}$, as a typical compound with 1D structure, has been reported by several groups, in which the synthesis methods and its electrochemical properties are investigated.²⁶⁻²⁹ However, ⁴⁰there are few reports to explore its sensing properties. In this work, $Ni(SO₄)_{0.3}(OH)_{1.4}$ nanobelts (NSOH NBs) with uniform morphology were synthesized on a large scale using a facile hydrothermal method. The sensors were fabricated using the NSOH NBs as sensitive material. Electrical characteristics ⁴⁵and humidity sensing properties were investigated, which showed high sensitivity, good long-term stability and fast

response. The $Ni(SO₄)_{0.3}(OH)_{1.4}$ nanobelts were synthesized in 25 mL

de-ionized water, together with 2.0 mmol nickel acetate and ⁵⁰2.0 mmol sodium sulfate at 150 °C for 20 h. The morphology of the samples was examined by scanning electron microscope (SEM) with Hitachi-4800. Fig. 1a shows the typical SEM image which indicates the product consists of large quantity of nanobelts with the length about 10 to 20 μ m. The phase ⁵⁵purity and crystal structure of the nanobelts was characterized

- by X-ray Diffraction (XRD) on a JEOL X-ray diffractomer using Cu-kα radiation at 40 kV and 250 mA, as shown in Fig. 1b. Obviously, all the diffraction peaks can correspond well to standard card of monoclinic paraotwayite (JCPDS No: 41-
- ⁶⁰1424). No peaks of impurities or other phases were detected. The XRD pattern of the sample after kept in air for one year is given in Fig. S1. It shows little change. Further details were carried out by transmission electron microscope (TEM) with JEOL JEM-3010. The TEM specimen was prepared by
- ⁶⁵placing a drop of the nanobelts dispersed in ethanol on a Cu grid covered with a holey carbon film. Fig. 1c reveals the beltlike morphology, according with SEM images. A highresolution TEM (HRTEM) image is observed in Fig. 1d, which displays an obvious crystalline lattice with interplane 70 spacing of 0.2208 nm, corresponding to the (10-6) plane of NSOH phase. The selected-area electron diffraction (SAED) pattern (Fig. S2) reveals the single crystal nature of the obtained material.

 75 Fig. 1 (a) SEM images (b) XRD pattern of the Ni(SO₄)_{0.3}(OH)_{1.4} nanobelts. (c) TEM and (d) HRTEM images of the $Ni(SO₄)_{0.3}(OH)_{1.4}$ nanobelts. The inset in (d) is the enlarged part of (d).

Humidity sensors based on $Ni(SO₄)_{0.3}(OH)_{1.4}$ nanobelts were fabricated by a simple drop method on interdigital gold ⁸⁰electrodes on ceramic substrate. The width and length of the

Fig. 2 (a, b) Real-time response of the RH sensor under different RHs. (c) Resistance of the sensor under each RH. (d) The ratio under different RH. The red line is the exponential fitting between the ratio and RH.

- interdigital electrode are about 2.8 and 3.5 mm, respectively. ⁵The strip width of each finger is about 90 µm and the distance between each strip electrode is about 70 µm. For preparation, the ceramic substrate was cleaned by diluted HCl, acetone and de-ionized water respectively. The as-synthesized NSOH NBs were mixed with ethanol by ultrasonic for 1 h. After that, a
- ¹⁰drop of the suspension was coated on the substrate. The device was heated at 60 °C for the volatilization of ethanol. Bare Au interdigital electrodes and electrodes with sensing material are shown in the inset of Fig. S2. The sensing material formed thin film in light-green color. The ¹⁵corresponding current-voltage (*I-V*) curve was obtained by an
- Agilent 4156C precision semiconductor parameters analyzer, as shown in Fig. S3. The *I-V* curve was measured in the air ambient.
- The humidity sensing properties were measured by using a ²⁰high precision sensor testing system NS-4003 series (China Zhong-Ke Micro-nano IOT Ltd). Temperatures and humidities were precisely controlled through a climate test chamber C 180-40 (Weiss-voetsch Environmental Testing instruments, Tai Cang Co., Ltd). The chamber volume is 190 L. A ²⁵schematic illustration of the sensor test system is shown in Fig.
- S4. The relative humidity (RH) and temperature of the atmosphere were 60% and 20 °C, respectively.

The resistance as a function of RH in aspect of time of the sensor was tested by NS-4003 series with an applied DC ³⁰voltage of 5 V. The resistance variation as a function of RH at

a constant temperature of 20 ℃ is presented in Fig. 2. Fig. 2a is the real-time resistance response between ambient air (60%) and different lower RH (15%, 20%, 25%, 30%, 35%, 40%, 50%) at 20 ℃. It indicates a strong influence of humidity on ³⁵the resistance of the sensor which increases with decreasing RH. Under 60% RH, the resistance $(R_{60\%})$ is about $2.5 \times 10^6 \Omega$, which quickly increases and rapidly reaches $8.32 \times 10^9 \Omega$ when the sensor is put in the chamber of 15% RH. After the RH is back to 60%, the resistance abruptly decreases and then ⁴⁰ gradually returns to original 2.5×10^6 Ω. The corresponding response time and recovery time (defined as the time required to reach 90% of the final equilibrium value) are about 3 s. In Fig. 2b, the measurement is based on dynamic switches of the sensor between ambient air (60%) and relatively higher RH. ⁴⁵After exposed to 70%, 80%, and 90% RH, the sensor displays corresponding resistance of about 7.94 \times 10⁵, 4.88 \times 10⁵, and 3.21×10^5 Ω , respectively. The response and recovery time is longer than that when RH changes from 60% to lower humidities, which is obvious to observe in the latter two 50 cycles shown in Fig. 2(b). The resistance (log $(Ω)$) as a function of RH is given in Fig. 2c, which shows that the resistance of the film decreases monotonically with increasing RH in the test range of $15\% - 90\%$. Obviously, the resistance of the film changes by more than four orders of magnitude ⁵⁵ (from 10⁵ Ω to nearly 10¹⁰ Ω), showing ultra-high sensitivity compared with many metal oxide humidity sensors.^[6, 30-32] The ratio *S* is defined as $R_{15\%}/R$, and *R* is the resistance under

higher RH, that is, 20%, 25%, 30%, 35%, 40%, 50%, 60%,

Fig. 3 The resistance decreases with RH at different temperatures.

70%, 80%, and 90% RH. The result is shown in Fig. 2d. *S* increases largely with RH. From 15% to 30%, it linearly

- ⁵increases with slope 1. From 35% to 50%, *S* linearly increases with slope 71.7. From 60% to 90%, *S* linearly increases with slope 753. The performance of the sensor in dry air was also measured. The resistance R_{dry} is 3.14×10¹⁰ Ω . Its corresponding sensitivity is given in Fig. S5.
- 10 To check its humidity sensitive characteristics of the sensor under different temperatures, resistance variations as a function of time were shown in Fig. 3. The measurements were carried out by RH changing from 15%, 20%, 25%, 30%, 40%, 50%, 60%, 70% to 80% when the temperature was
- 15 controlled to be 40, 50, 60, 70, 80, 90 °C, respectively. The sensor resistance decreases with RH, consistent with the result before. The result shows that the sensor exhibits similar properties under different temperatures.

The long-term stability is an important parameter for the ²⁰practical applications of humidity sensor. Herein, the stability of the NSOH NBs sensor was monitored under different humidity conditions for 3 months. Fig. 4 shows the real-time resistance response of the sensor with different RHs at 20 ℃ after 3 months. It can be observed that the resistance just 25 varies slightly less than 5% over the entire humidity region,

Fig. 4 The real-time resistance response with different RHs after 3 months.

³⁰indicating the NSOH NBs sensor displays excellent long-term stability.

The good sensing ability of the $Ni(SO₄)_{0.3}(OH)_{1.4}$ nanobelts sensor to humidity probably can be attributed to its structure and OH⁻, SO_4^2 ⁻ groups of $Ni(SO_4)_{0.3}(OH)_{1.4}$ ³⁵nanobelts. Literatures have shown that 1D nanomaterial with high specific surface is highly advantageous for gas sensing, as it has a large exposure of surface atoms providing more active sites for the adsorption of gas sensing reaction, as it has a large exposure of surface atoms providing more active sites ⁴⁰for the adsorption of gas molecules and hence promoting the surface reactions. $14-15, 30$

Humidity sensing is related to water adsorption and desorption process.³³⁻³⁵ According to J. H. Anderson et al., protons could act as charge carriers during humidity sensing 45 process.³⁶ At low humidity, tips and defects of the nanomaterial present a high local charge density and a strong electrostatic field, which promotes water dissociation.³³ The dissociation provides protons and hydroxyl groups. Protons hop along the nanobelt, contributing to the conductance. ⁵⁰Water molecule layer is then physisorbed on the hydroxyl groups. At higher humidity, further physisorbed water layers are adsorbed on the first water layer. H_3O^+ appears and serves as a charge carrier. $37-40$ In our work, OH groups exists initially in NSOH NBs. It could be effective sites to adsorb ⁵⁵water molecules, which is believed to be a great contribution for NSOH NBs to exhibit a better performance. Fig. S7a shows nanobelt without the chemical composition OH- . The OH⁻ shown in Fig. S5a is formed by dissociation of water and then absorbed on the surface of the nanobelts. While the 60 nanobelt contains OH as shown in Fig. S7b, the water dissociation also happens. In the same time, it has more active sites to adsorb water molecules, thus more protons take part in the conduction, leading to the decrease of the resistance. When humidity gets even higher, more water molecules layers ⁶⁵are adsorbed on the humidity sensor. Liquid water layers form on the surface of the nanobelt. In experimental section, *S* increases with humidity, with different slope in three RH regions. The response/recovery time also increase when RH changes from 60% to higher humidites. These experimental ⁷⁰results could be related to the three humidity sensing process.

In conclusion, we reported the growth of single crystal NSOH NBs by a hydrothermal method. Sensitive humidity sensor was then fabricated with the nanobelts coated on ceramic substrate with Au interdigital electrodes. By ⁷⁵measuring resistance of the device at different humidities and temperatures, the humidity sensing properties were studied. Resistance of the humidity sensor decreased monotonically with increasing RH. At 20 ℃, the resistance changes of more than four orders of magnitude was observed when NSOH NBs ⁸⁰device was measured in 15% and 90% RH, respectively. The real-time response of the device show its rapid response and recovery time less than 3 s. Three months later, the measurement results show little variation. High sensitivity, fast response, long-term stability of the nanobelt sensor is 85 potentially useful for humidity sensing. The high performance of the humidity sensor can to be contributed to its 1D morphology and its chemical composition.

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‡ Footnotes should appear here. These might include comments relevant

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